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Product data sheet

1. Product profile

1.1 General description

NPN/PNP transistor pair connected as push-pull driver in a SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Switching transistors in push-pull configuration
- Application-optimized pinout
- Space-saving solution
- Internal connections to minimize layout effort
- Reduces component count

1.3 Applications

- MOSFET driver
- Power bipolar transistor driver
- Output current booster for operational amplifier

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|------------------------------|--|------|-----|-----|------|
| Per transis | stor; for the PNP transistor | with negative pola | rity | | | |
| V _{CEO} | collector-emitter voltage | open base | - | - | 40 | V |
| I _C | collector current | | - | - | 0.6 | А |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | - | 1 | A |



2. Pinning information

| Table 2. | Pinning | | |
|----------|------------------|--------------------|---------------------------|
| Pin | Description | Simplified outline | Symbol |
| 1 | base TR1, TR2 | | |
| 2 | collector TR2 | | |
| 3 | collector TR2 | 0 | |
| 4 | emitter TR1, TR2 | | |
| 5 | collector TR1 | | |
| 6 | collector TR1 | | 1 2 3 <i>006aaa659</i> |

3. Ordering information

| Table 3. Ordering information | | | | | |
|---------------------------------------|---------|--|---------|--|--|
| Type number | Package | | | | |
| | Name | Description | Version | | |
| PMD2001D | SC-74 | plastic surface-mounted package (TSOP6); 6 leads | SOT457 | | |

4. Marking

| Table 4. | Marking codes | |
|-----------|---------------|--------------|
| Type numb | per | Marking code |
| PMD2001D |) | 9E |

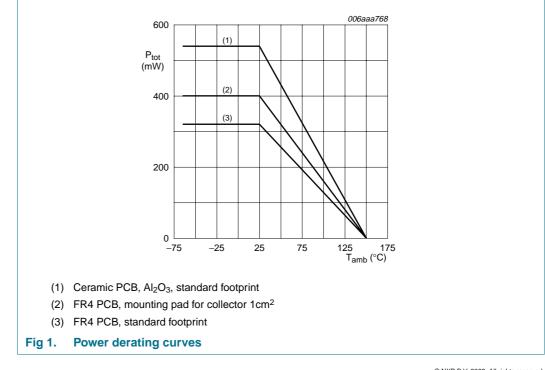
5. Limiting values

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|--------------------------------|--|-------|------|------|
| Per transis | stor; for the PNP transistor v | with negative polari | ty | | |
| V _{CBO} | collector-base voltage | open emitter | - | 40 | V |
| V _{CEO} | collector-emitter voltage | open base | - | 40 | V |
| I _C | collector current | | - | 0.6 | А |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | 1 | А |
| I _{BM} | peak base current | | - | 0.1 | А |
| | | single pulse; t _p ≤ 1 ms | - | 0.2 | A |
| Per device |) | | | | |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | [1] - | 320 | mW |
| | | | [2] _ | 400 | mW |
| | | | [3] _ | 540 | mW |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1cm².

[3] Device mounted on a ceramic PCB, AI_2O_3 , standard footprint.



Rev. 02 - 28 August 2009

MOSFET driver

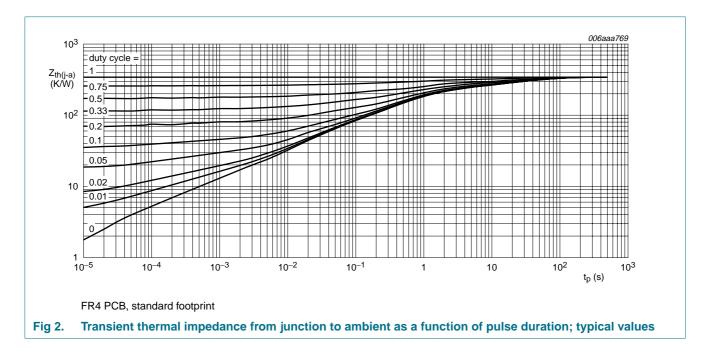
6. Thermal characteristics

| Table 6. | Thermal characteristics | | | | | |
|--|-------------------------|-------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-a)} thermal resistance from junction to ambient | | in free air | <u>[1]</u> _ | - | 390 | K/W |
| | junction to ambient | | [2] _ | - | 315 | K/W |
| | | | [3] | - | 230 | K/W |

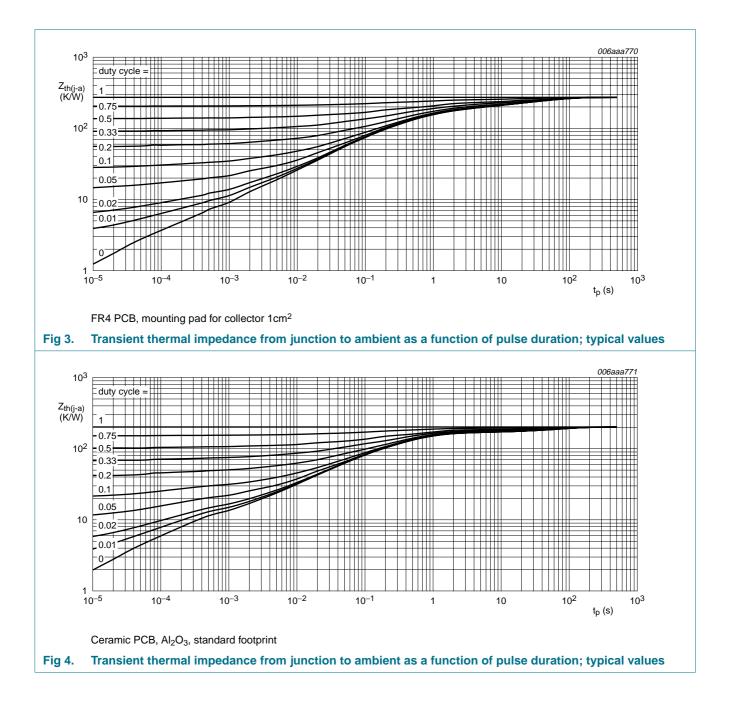
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.







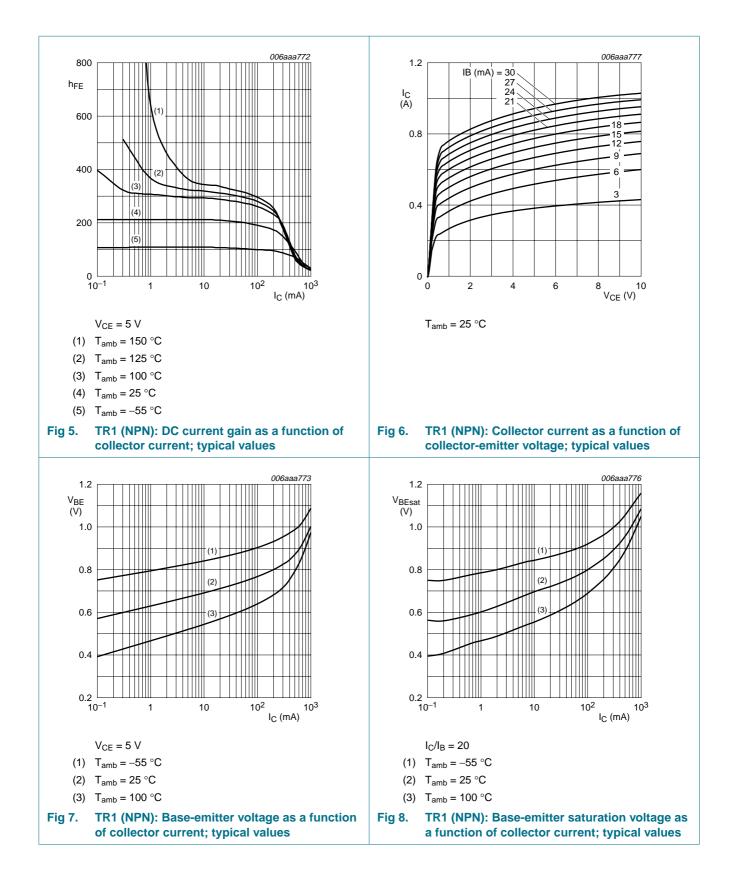
7. Characteristics

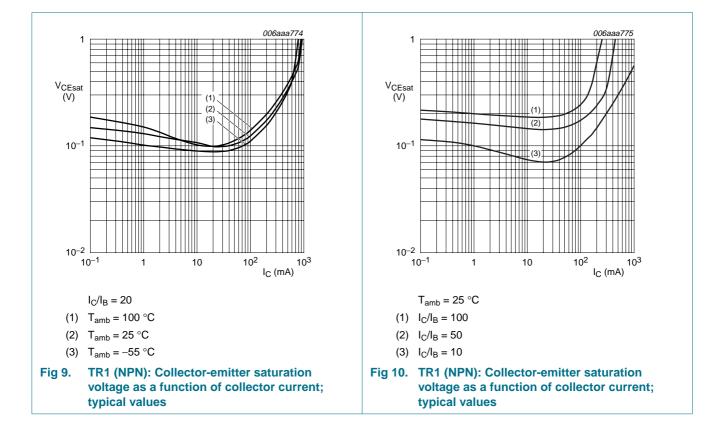
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------------------|---------------------------------------|--|------------|-----|-------|------|------|
| Per NPN | I transistor | | | | | | |
| I _{CBO} | CBO collector-base cut-off current | $V_{CB} = 40 \text{ V}; \text{ I}_{E} = 0 \text{ A}$ | | - | - | 10 | nA |
| | | $V_{CB} = 40 \text{ V}; I_E = 0 \text{ A};$ T _j = 150 °C | | - | - | 10 | μA |
| h _{FE} | DC current gain | V_{CE} = 5 V; I_C = 1 mA | | 100 | 210 | - | |
| | | $V_{CE} = 5 \text{ V}; I_{C} = 200 \text{ mA}$ | | 100 | 170 | 300 | |
| | | $V_{CE} = 5 \text{ V}; I_{C} = 500 \text{ mA}$ | [1] | 50 | 100 | - | |
| V _{CEsat} | collector-emitter | $I_{C} = 200 \text{ mA}; I_{B} = 20 \text{ mA}$ | | - | 150 | 250 | mV |
| | saturation voltage | $I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}$ | [1] | - | 300 | 500 | mV |
| V _{BEsat} | base-emitter | $I_{C} = 200 \text{ mA}; I_{B} = 20 \text{ mA}$ | | - | 0.86 | 1 | V |
| | saturation voltage | $I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}$ | [1] | - | 0.95 | 1.1 | V |
| Per PNF | • transistor | | | | | | |
| I _{CBO} | | $V_{CB} = -40$ V; $I_E = 0$ A | | - | - | -10 | nA |
| current | current | $V_{CB} = -40 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$ | | - | - | -10 | μA |
| h _{FE} | DC current gain | V_{CE} = -5 V; I_C = -1 mA | | 100 | 180 | - | |
| | | V_{CE} = –5 V; I_{C} = –200 mA | | 80 | 125 | 300 | |
| | | V_{CE} = –5 V; I_{C} = –500 mA | [1] | 50 | 80 | - | |
| V _{CEsat} | collector-emitter | I_C = -200 mA; I_B = -20 mA | | - | -130 | -250 | mV |
| | saturation voltage | $I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$ | <u>[1]</u> | - | -280 | -500 | mV |
| V _{BEsat} | base-emitter | $I_C = -200 \text{ mA}; I_B = -20 \text{ mA}$ | | - | -0.87 | -1 | V |
| | saturation voltage | $I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$ | <u>[1]</u> | - | -0.98 | -1.1 | V |
| Per dev | ice | | | | | | |
| t _d | delay time | $I_{C} = 0.15 \text{ A}; V_{I} = 7.5 \text{ V}$ | | - | 3 | - | ns |
| t _r | rise time | | | - | 3 | - | ns |
| t _{on} | turn-on time | | | - | 6 | - | ns |
| t _s | storage time | | | - | 2 | - | ns |
| t _f | fall time | | | - | 3 | - | ns |
| t _{off} | turn-off time | | | - | 5 | - | ns |

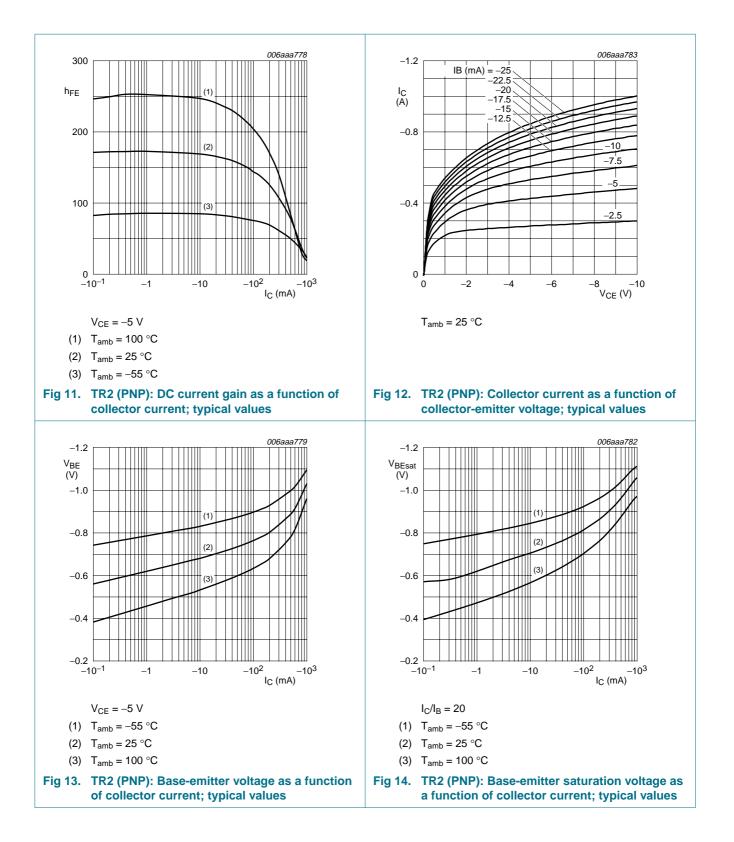
[1] Pulse test: $t_p \leq 300 \ \mu s; \ \delta \leq 0.02$

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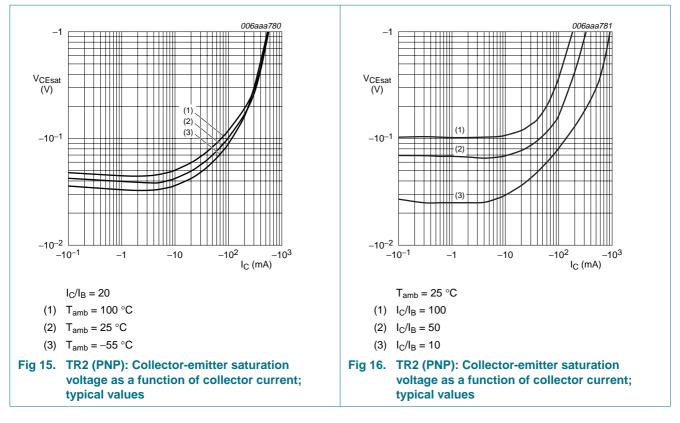
PMD2001D MOSFET driver



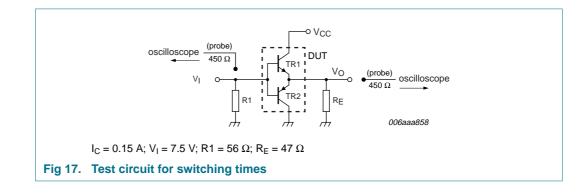




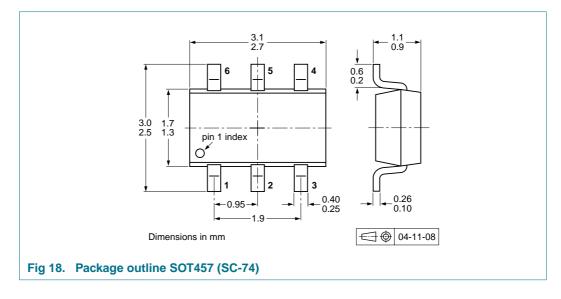
PMD2001D_2 Product data sheet



8. Test information



9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

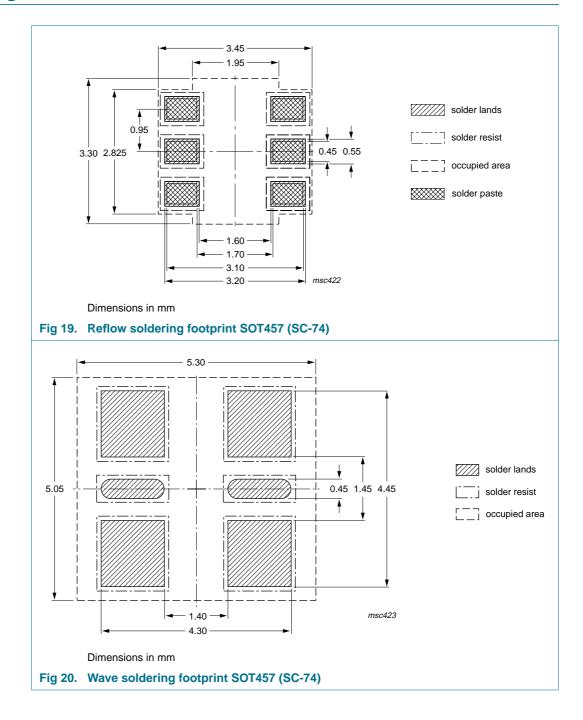
| Type number | Package | Description | Packing | g quantity |
|---------------|---------|------------------------------------|---------------------|------------|
| | | | 3000 | 10000 |
| PMD2001D SOT4 | SOT457 | 4 mm pitch, 8 mm tape and reel; T1 | ^[2] -115 | -135 |
| | | 4 mm pitch, 8 mm tape and reel; T2 | <u>3</u> -125 | -165 |

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] T1: normal taping

[3] T2: reverse taping

11. Soldering



12. Revision history

| Table 9. Revisio | n history | | | |
|------------------|----------------------------------|--|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| PMD2001D_2 | 20090828 | Product data sheet | - | PMD2001D_1 |
| Modifications: | | neet was changed to reflect w legal definitions and dis | | |
| | Figure 20 "V | Vave soldering footprint So | <u> </u> | d |
| PMD2001D_1 | 20060925 | Product data sheet | - | - |

13. Legal information

13.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PMD2001D_2 Product data sheet

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